

# **High Efficient Surface Mount Rectifiers**

#### FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- Ultrafast recovery time for high efficiency
- Built-in strain relief
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### MECHANICAL DATA

#### Case: DO-214AC (SMA)

Molding compound, UL flammability classification rating 94V-0 Base P/N with suffix "G" on packing code - Green compound (halogen-free) Base P/N with prefix "H" on packing code - AEC-Q101 qualified **Terminal:** Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 1A whisker test with prefix "H" on packing code meet JESD 201 class 2 whisker test **Polarity:** Indicated by cathode band **Weight:** 0.06 g (approximately)





DO-214AC (SMA)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)									
PARAMETER	SYMBOL	US	US	US	US	US	US	US	UNIT
	STIVIDUL	1A	1B	1D	1G	1J	1K	1M	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I <sub>F(AV)</sub>	1			А				
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30			A				
Maximum instantaneous forward voltage (Note 1) @ 1 A	V <sub>F</sub>	1.0 1.7			V				
Maximum reverse current @ rated VR $T_J$ =25 $^{\circ}C$ $T_J$ =125 $^{\circ}C$	I <sub>R</sub>	5 150		μA					
Maximum reverse recovery time (Note 2)	Trr	50 75			ns				
Typical junction capacitance (Note 3)	Cj	15 10			pF				
Typical thermal resistance	R <sub>θjL</sub> R <sub>θjA</sub>	27 75		<sup>o</sup> C/W					
Operating junction temperature range	TJ	- 55 to +150			°C				
Storage temperature range	T <sub>STG</sub>	- 55 to +150			°C				

Note 1: Pulse test with PW=300µs, 1% duty cycle

Note 2: Reverse Recovery Test Conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.



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ORDERING INFORMATION					
PART NO.	AEC-Q101	PACKING CODE	GREEN COMPOUND	PACKAGE	PACKING
	QUALIFIED		CODE		
US1x (Note 1) N/A		R3		SMA	1,800 / 7" Plastic reel
	R2		SMA	7,500 / 13" Paper reel	
	Drofix "LI"	M2	Suffix "G"	SMA	7,500 / 13" Plastic reel
		F3		Folded SMA	1,800 / 7" Plastic reel
		F2		Folded SMA	7,500 / 13" Paper reel
		F4		Folded SMA	7,500 / 13" Plastic reel
	N/A	E3		Clip SMA	1,800 / 7" Plastic reel
		E2		Clip SMA	7,500 / 13" Plastic reel

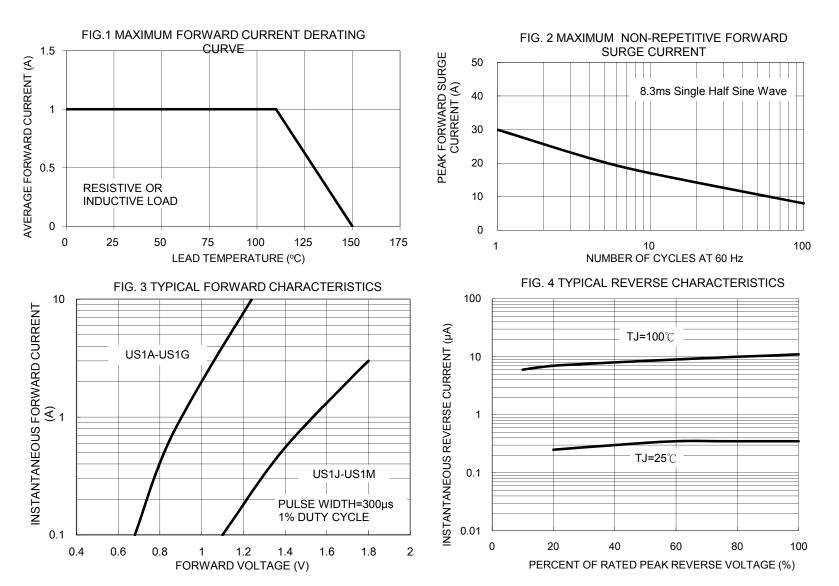
Note 1: "x" defines voltage from 50V (US1A) to 1000V (US1M)

# EXAMPLE

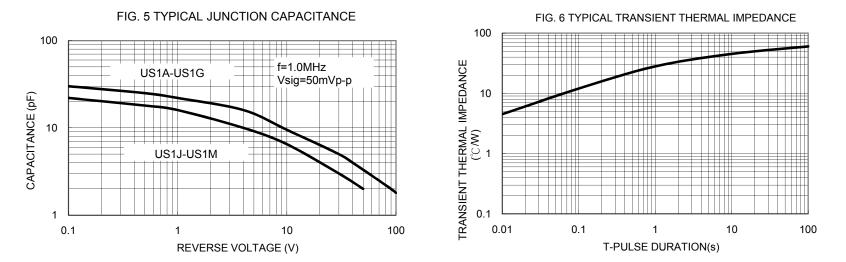
PREFERRED P/N	PART NO.	AEC-Q101 QUALIFIED	PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION
US1M R3	US1M		R3		
US1M R3G	US1M		R3	G	Green compound
US1MHR3	US1M	Н	R3		AEC-Q101 qualified

# **RATINGS AND CHARACTERISTICS CURVES**

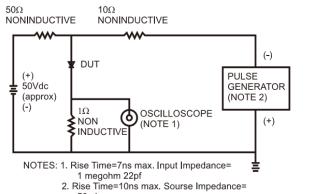
(TA=25 $^{\circ}$ C unless otherwise noted)



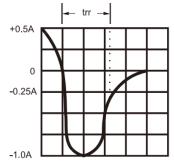
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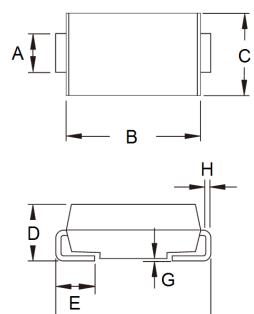




50 ohms

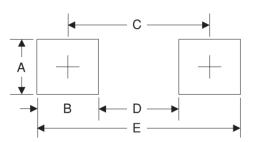


### PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)			
	Min Max		Min	Мах		
А	1.27	1.58	0.050	0.062		
В	4.06	4.60	0.160	0.181		
С	2.29	2.83	0.090	0.111		
D	1.99	2.50	0.078	0.098		
Е	0.90	1.41	0.035	0.056		
F	4.95	5.33	0.195	0.210		
G	0.10	0.20	0.004	0.008		
Н	0.15	0.31	0.006	0.012		

# SUGGESTED PAD LAYOUT



F =

F

Symbol	Unit (mm)	Unit (inch)
А	1.68	0.066
В	1.52	0.060
С	3.93	0.155
D	2.41	0.095
E	5.45	0.215

#### **MARKING DIAGRAM**



- P/N = Specific Device Code
- G = Green Compound
- YW = Date Code
  - Factory Code



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